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TR	TRANSMITTAL			Filing Date	June 26, 2	2003			
	_	RM		First Named Inventor	Donald L.				
	• •	1 (10)		Art Unit	2811				
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		This Submission		Attorney Docket Number	MI22-2236	6			
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	Amendment/Reply			Petition Petition to Convert to a Provisional Application	Appeal Communication to TC (Appeal Notice, Brief, Reply Brief) Proprietary Information				
	fter Final			Power of Attorney, Revocation			Status Letter		
		declaration(s)		Change of Correspondence	Address		Status Letter Other Enclosure(s) (please Identify		
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		DFR 1.52 or 1.53		However should a fee be determined as owing, please charge such fee to Deposit					
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Firm Name	Wells Ŝ	t. John P.S.							
Signature		1 Bl							
Printed name	Robert 0	C. Hýta							
Date	10	1/25 les			Reg. No.	46,791	11		
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This collection of information is required by 37 CFR 1.5. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.11 and1.14. This collection is estimated to 2 hours to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Patent Application Serial No	10/609,311
Filing Date	
Inventor	
Assignee	Micron Technology, Inc.
Group Art Unit	
Examiner	
Attorney Docket No	MI22-2236
Customer No	021567
Title: Semiconductor Processing Patterni	ing Methods and Constructions

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

References -- See Attached Form PTO-1449

The attached form PTO-1449 is submitted in compliance with 37 CFR §1.56. Copies of all references are attached. No admission is made regarding whether all the listed references are prior art.

Citation of the referenced art is respectfully requested.

This Supplemental Information Disclosure Statement is being filed before the mailing date of a first Office Action. There, no fee is believed to be required. However, in the event that a fee is required for filing this Information Disclosure Statement, please charge the fee specified under 37 C.F.R. § 1.17(p) to Deposit Account No. 23-0925.

By:

Respectfully submitted,

Dated: <u>10/25/64</u>

Robert C. I

Reg. No. 46,791

Form PTO-1449

U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE

ATTY. DOCKET NO. MI22-2236

SERIAL NO. 10/609,311

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APPLICANT: Donald L. Yates

FILING DATE June 26, 2003

GROUP 2811

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	AC	5,998,264	12/1999	Wu	438	260		
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	Al	2003/0045078 A1	03/2003	Ahn et al.	438	585		
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	لم	FP 0 851 473 A2	01/1998	I FPO				
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